Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

3.145 inches

Mounting Facility Quantity:

1

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

Do-8

Mounting Method:

Threaded stud

Overall Width Across Flats:

Between 1.031 inches and 1.063 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

100.0 working peak reverse voltage and 200.0 nonrepetitive peak reverse voltage

Current Rating Per Characteristic:

100.00 amperes forward current, average and 24.00 amperes forward current, average major

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius case

Terminal Type And Quantity:

1 threaded stud and 1 insulated wire lead

Specification Data:

80131-release 4796 professional/industrial association specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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